



DMP2006UFG

PowerDI3333-8

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>C</sub> = +25°C		
-20V	$5.5m\Omega @ V_{GS} = -4.5V$	-40A		
-201	7.5mΩ @ V <sub>GS</sub> = -2.5V	-40A		

### Description

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

- Load Switch
- Power Management Functions

# Features

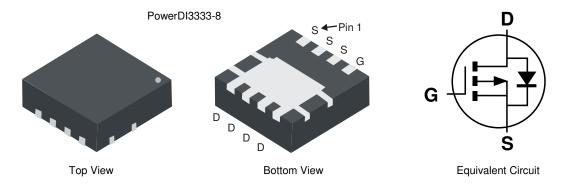
- Low R<sub>DS(ON)</sub> ensures on state losses are minimized
- Small form factor, thermally efficient package enables higher density end products

20V P-CHANNEL ENHANCEMENT MODE MOSFET

- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: PowerDI<sup>®</sup>3333-8
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 🔞
- Weight: 0.030 grams (Approximate)



### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2006UFG-7	PowerDI3333-8	2,000/Tape & Reel
DMP2006UFG-13	PowerDI3333-8	3,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

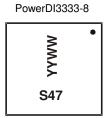
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**

Notes:



S47 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17 = 2017) WW = Week Code (01 to 53)

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### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	-20	V		
Gate-Source Voltage	V <sub>GSS</sub>	±10	V		
Continuous Drain Current (Note 5) $V_{GS}$ = -4.5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ $T_C = +25^{\circ}C$	ID	-17.5 -14.0 -40	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	-80	A	
Maximum Continuous Body Diode Forward Current	Is	-2.2	A		
Avalanche Current (Note 7) L = 0.1mH	IAS	-23	A		
Avalanche Energy (Note 7) L = 0.1mH			E <sub>AS</sub>	28	mJ

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	Р	2.3	w
Total Fower Dissipation (Note 5)	$T_{\rm C} = +25^{\circ}{\rm C}$ $P_{\rm D}$		41	vv
Thermal Resistance, Junction to Ambient	(Note 5)	Р	54	°C/W
	(Note 6)	$R_{\theta JA}$	136	
Thermal Resistance, Junction to Case (Note 5)	R <sub>eJC</sub>	3.0		
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

### **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)						÷	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	—	—	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	—	-1	μΑ	$V_{DS} = -16V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.4	_	-1.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
		_	4.2	5.5		$V_{GS} = -4.5V, I_D = -15A$	
Static Drain-Source On-Resistance		—	5.4	7.5	mΩ	$V_{GS} = -2.5V, I_D = -10A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	8	12	11152	$V_{GS} = -1.8V, I_D = -1A$	
		_	12	17		$V_{GS} = -1.5V, I_D = -1A$	
Diode Forward Voltage	V <sub>SD</sub>	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -10A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C <sub>iss</sub>	—	5404	7500		V <sub>DS</sub> = -10V, V <sub>GS</sub> = 0V f = 1.0MHz	
Output Capacitance	Coss	_	728	1000	pF		
Reverse Transfer Capacitance	Crss	—	612	900			
Gate Resistance	R <sub>G</sub>	_	3.8	8	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	—	64	100			
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	140	200	nC	Vע = -10V. א = -20A	
Gate-Source Charge	Q <sub>gs</sub>	_	8.5	15	no	$v_{DD} = -10v, I_D = -20A$	
Gate-Drain Charge	Q <sub>gd</sub>	_	17	30			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	9.1	20			
Turn-On Rise Time	t <sub>R</sub>	_	19	35		$V_{GS} = -4.5V, V_{DD} = -10V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	146	220	ns	$R_G = 1\Omega$ , $R_G = 1\Omega$ , $I_D = -10A$	
Turn-Off Fall Time	tF	_	104	150			
Reverse Recovery Time (Note 9)	t <sub>RR</sub>	_	61	100	ns	I <sub>F</sub> = -10A, di/dt = 100A/µs	
Reverse Recovery Charge (Note 9)	Q <sub>RR</sub>	_	44	70	nC	I <sub>F</sub> = -10A, di/dt = 100A/μs	

 R<sub>0JA</sub> is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. R<sub>0JC</sub> is guaranteed by design while R<sub>0JA</sub> is determined by the user's board design.

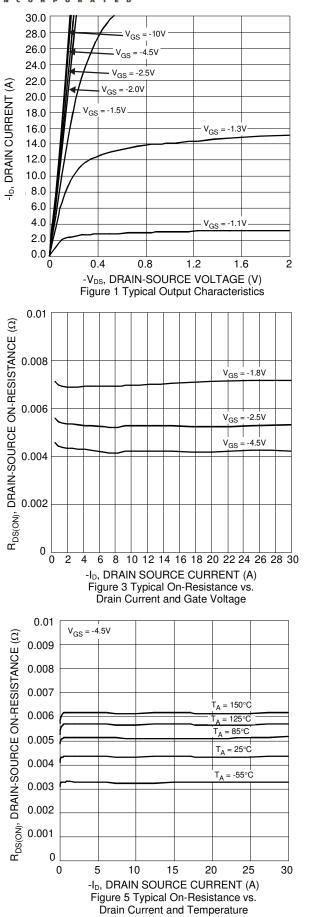
6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

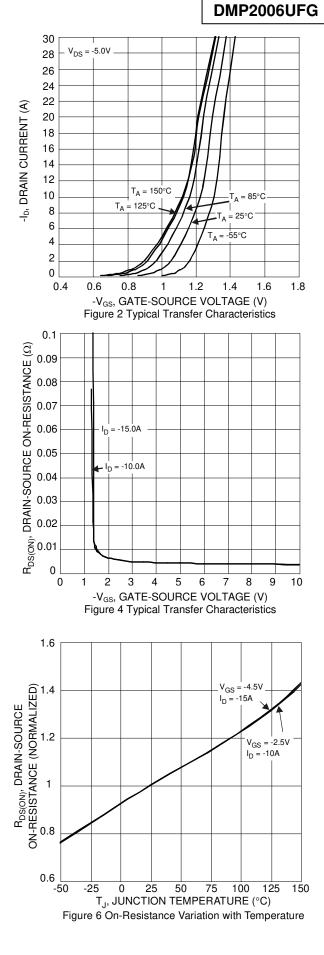
7. UIS in production with L = 0.1mH,  $T_J$  = +25°C.

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.



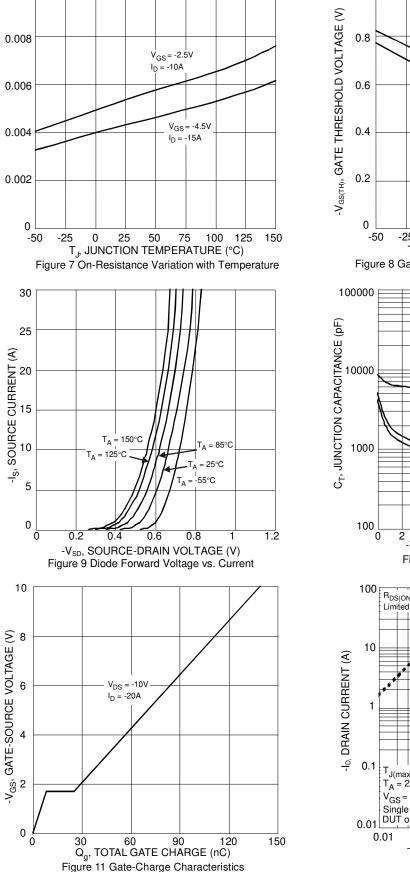




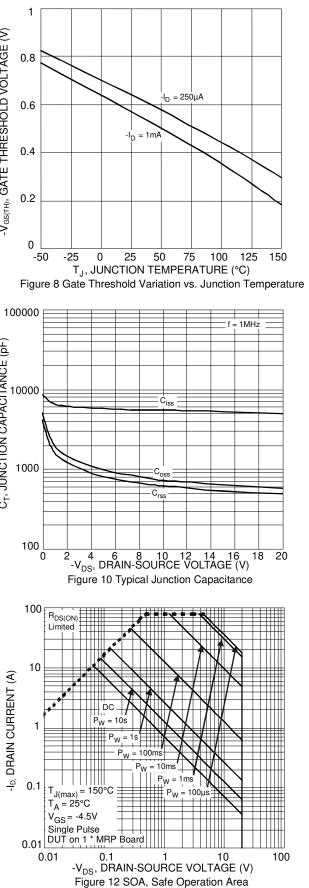


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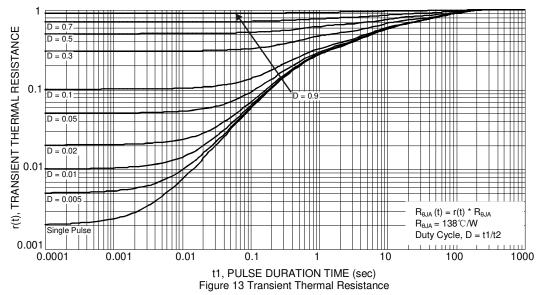
 $R_{\text{DS}(\text{ON})},$  DRAIN-SOURCE ON-RESISTANCE  $(\Omega)$ 



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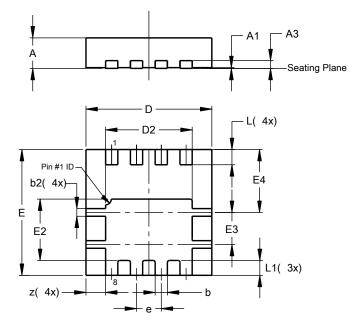




# Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

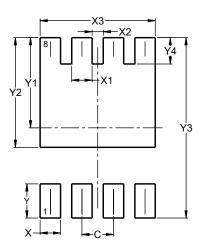
#### PowerDI3333-8



PowerDI3333-8						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	-	-	0.203			
b	0.27	0.37	0.32			
b2	0.15	0.25	0.20			
D	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
Е	3.25	3.35	3.30			
E2	1.56	1.66	1.61			
E3	0.79	0.89	0.84			
E4	1.60	1.70	1.65			
е	-	-	0.65			
L	0.35	0.45	0.40			
L1	_	_	0.39			
Z	-	-	0.515			
All I	All Dimensions in mm					

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI3333-8

Dimensions	Value (in mm)			
С	0.650			
Х	0.420			
X1	0.420			
X2	0.230			
X3	2.370			
Y	0.700			
Y1	1.850			
Y2	2.250			
Y3	3.700			
Y4	0.540			

Document number: DS36802 Rev. 5 - 2

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